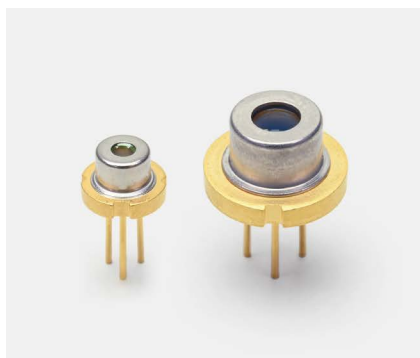


Pulsed laser diode (PLD)

L11348-307-05 L11649-120-04



High-power pulsed laser diode, Peak emission wavelength: 870 nm

L11348-307-05 and L11649-120-04 are pulse-driven multimode laser diodes that achieve high peak output. These are suitable for applications such as laser rangefinders, security, management, and monitoring.

Features

- **Emitter**
3-stack (L11348-307-05)
Single emitter (L11649-120-04)
- **Peak emission wavelength: 870 nm typ.**
- **Emission area (design value):**
70 $\mu\text{m} \times 10 \mu\text{m}$ (L11348-307-05)
230 $\mu\text{m} \times 1 \mu\text{m}$ (L11649-120-04)

Applications

- **Rangefinders**
- **Security (intrusion detection, obstacle detection)**
- **Position and shape measurement**

Absolute maximum ratings (Tcase=25 °C, unless otherwise noted)

Parameter	Symbol	L11348-307-05	L11649-120-04	Unit
Pulse forward current	IFP	10	25	A
Reverse voltage	VR	2		V
Pulse width	tw	100		ns
Duty ratio	DR	0.1		%
Operating temperature (case)*1	Tcase	-40 to +85		°C
Storage temperature*1	Tstg	-40 to +100		°C

*1: No dew condensation

When there is a temperature difference between a product and the surrounding area in high humidity environments, dew condensation may occur on the product surface. Dew condensation on the product may cause deterioration in characteristics and reliability.

Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

Electrical and optical characteristics (Tcase=25 °C, tw=50 ns, Repetition frequency fr=1 kHz, unless otherwise noted)

Parameter	Symbol	Condition	L11348-307-05*2			L11649-120-04*3			Unit
			Min.	Typ.	Max.	Min.	Typ.	Max.	
Peak radiant flux	ϕ_{ep}		18	21	-	19	22	-	W
Peak emission wavelength	λ_p		860	870	880	860	870	880	nm
Operating voltage	Vop		-	13	16	-	7	9	V
Spectral half width	$\Delta\lambda$		-	6	10	-	4	8	nm
Rise time	tr		-	-	2	-	-	2	ns
Wavelength temperature coefficient	-		-	0.25	-	-	0.25	-	nm/°C
Beam spread angle	Horizontal	FWHM	8	11	14	7	10	13	°
	Vertical		19	24	29	25	30	35	
Threshold current	Ith		-	0.5	-	-	0.8	-	A
Optical axis tilt	Horizontal	FWHM	-2	-	+2	-3	-	+3	°
	Vertical		-	-	-	-	-	-	
Emission area (design value)	-	Design value	-	70 \times 10	-	-	230 \times 1	-	μm
Position accuracy of emission point*4	-	$\Delta X, \Delta Y, \Delta Z$	-0.2	-	+0.2	-0.2	-	+0.2	mm

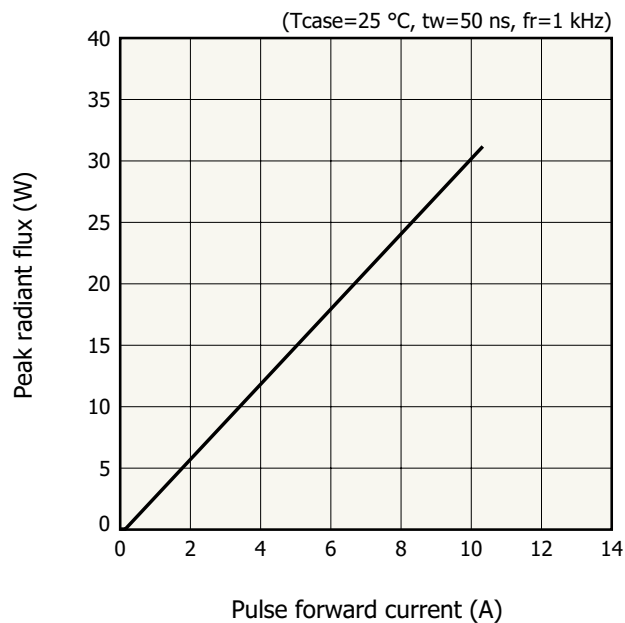
*2: IFP=7 A

*3: IFP=20 A

*4: Position of emitter center with respect to package base center

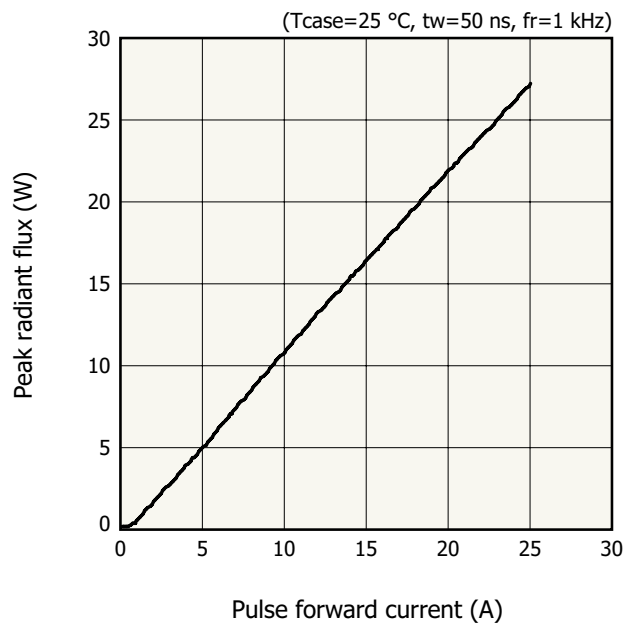
Peak radiant flux vs. pulse forward current (typical example)

L11348-307-05



KLD80017EA

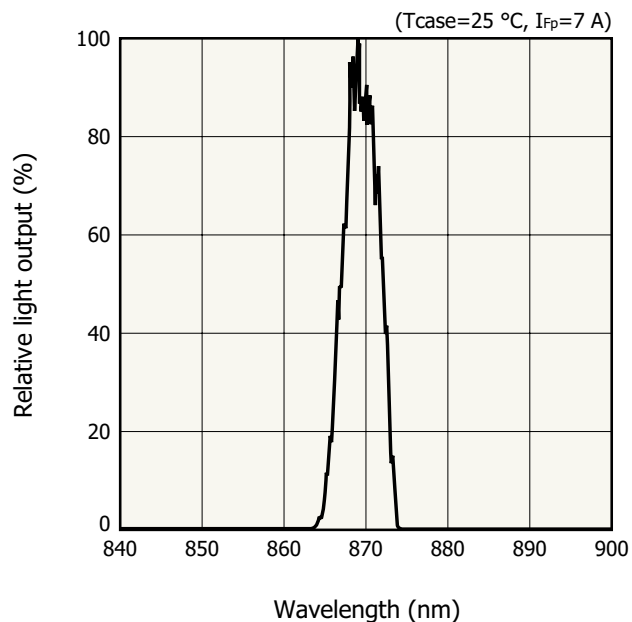
L11649-120-04



KLD80018EA

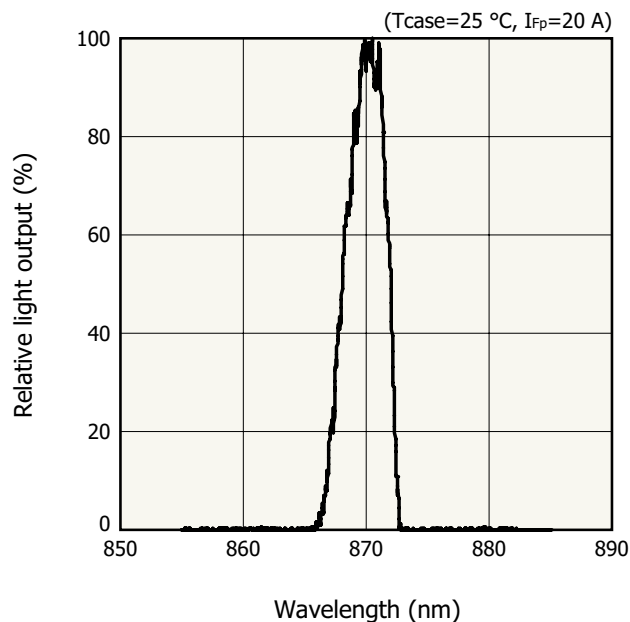
Emission spectrum (typical example)

L11348-307-05



KLD80019EA

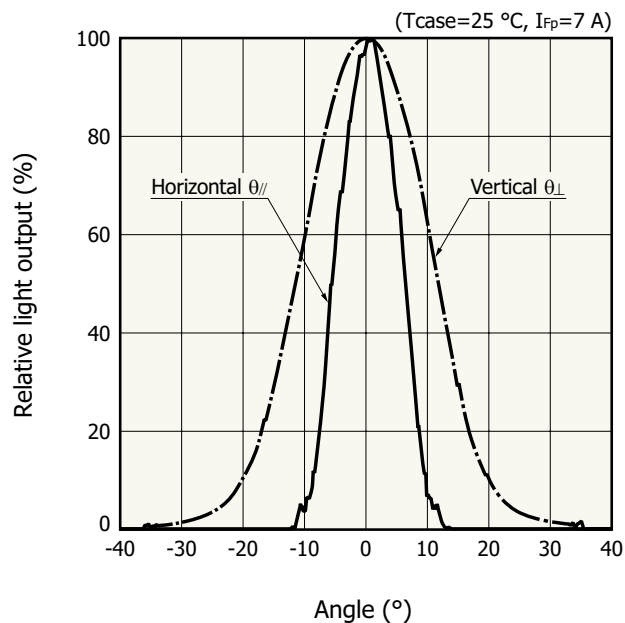
L11649-120-04



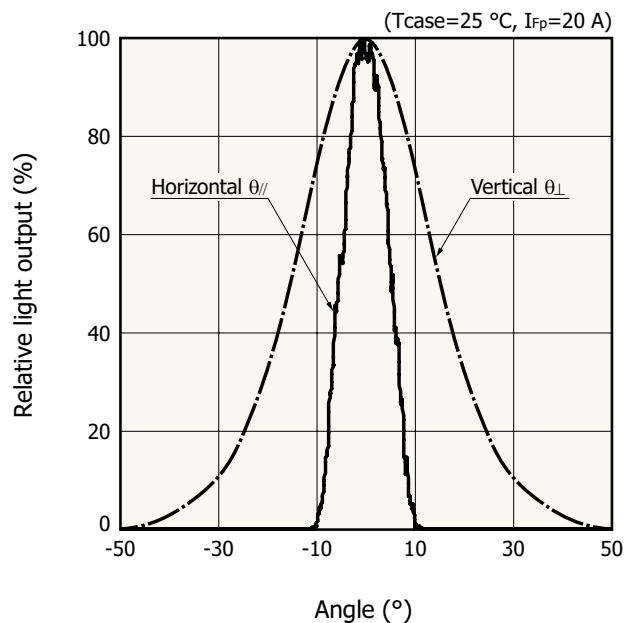
KLD80020EA

Directivity (typical example)

L11348-307-05

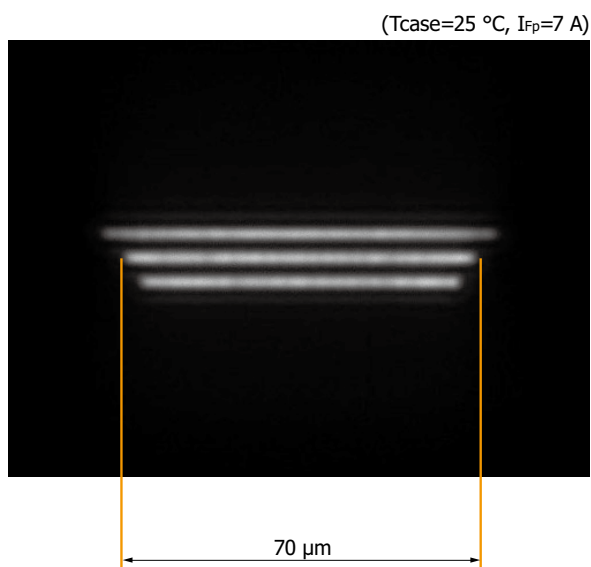


L11649-120-04

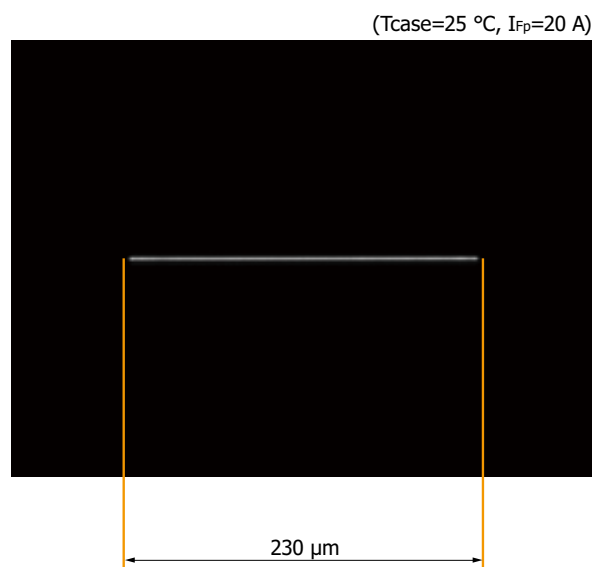


NFP emission pattern (typical example)

L11348-307-05

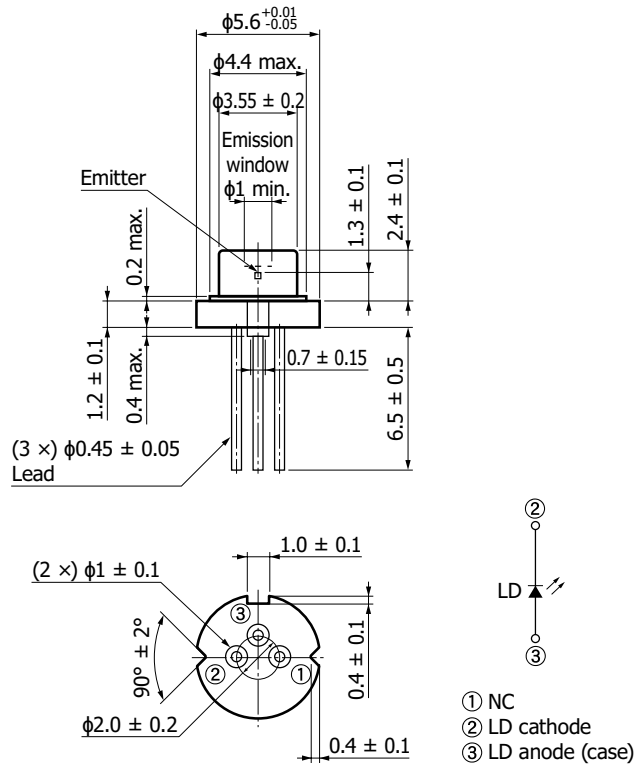


L11649-120-04

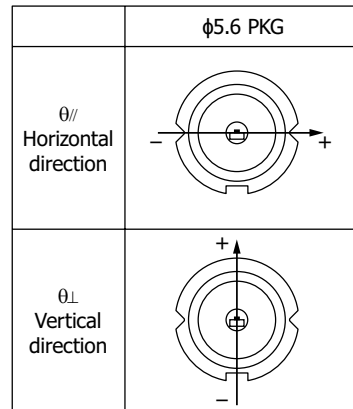


Dimensional outline (unit: mm)

L11348-307-05

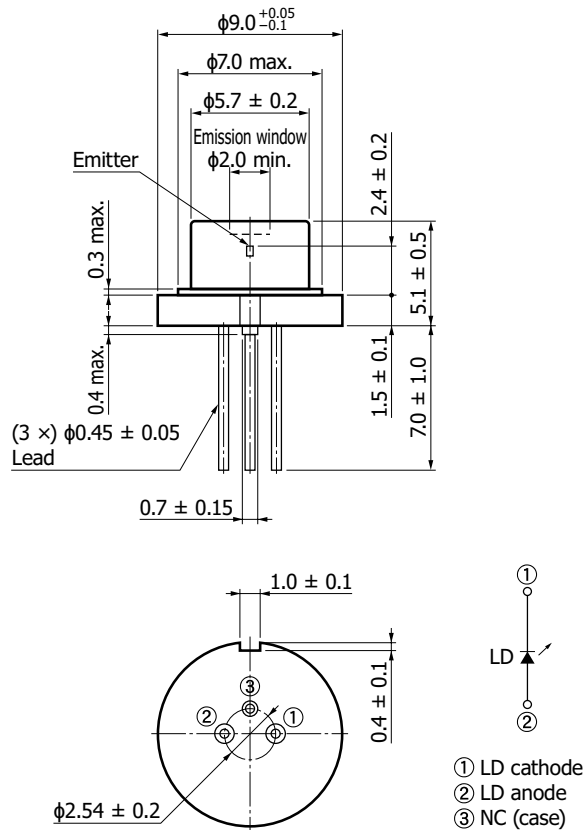


FFP horizontal and vertical directions relative to the package (front view)

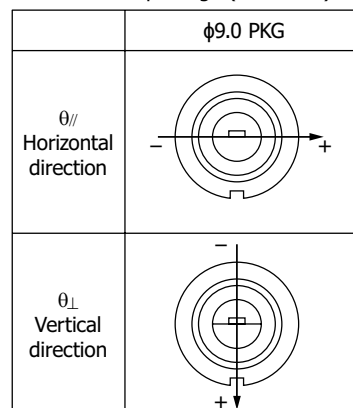


KLDA0003EA

L11649-120-04



FFP horizontal and vertical directions relative to the package (front view)



KLDA0004EA

Recommended soldering conditions

• Soldering temperature: 260 °C or less, within 5 seconds (1 second or less if the lead terminal length is 2 mm or less)

Note: When you set soldering conditions, check that problems do not occur in the product by testing out the conditions in advance.



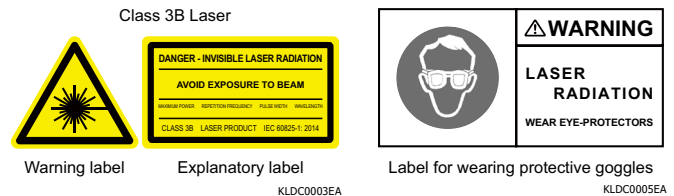
Warning (Class 3B laser)

Invisible laser emission: Avoid exposure to the beam

This product falls under the "Class 3B laser" in the classification of laser products according to IEC 60825-01. The laser light emitted by this product is an invisible laser light that cannot be seen by the naked eye. Observing the laser light directly is dangerous, and you should also avoid direct exposure to the skin. In addition, some conditions may cause skin damage or flammable substances to ignite.

When using equipment incorporating this product, please classify it according to IEC 60825-01.

Note: For more detailed information, please see [IEC 60825-1:2014].



Precautions

(1) Electrostatic countermeasures

To prevent damage due to static electricity, take electrostatic countermeasures such as grounding of workers, work benches, and work tools. For details, please refer to the related information "Precautions / Compound opto-semiconductors (photosensors, light emitters)". Also protect this device from surge voltages which might be caused by peripheral equipment.

(2) Reflected light

The product will be destroyed if it is irradiated with laser light, such as by regular reflection. When using this product, use extra caution to avoid irradiation of reflected light.

Related information

www.hamamatsu.com/sp/ssd/doc_en.html

■ Precautions

- Disclaimer
- Safety consideration / Opto-semiconductor products
- Precautions / Compound opto-semiconductors (photosensors, light emitters)

The content of this document is current as of June 2025.

Product specifications are subject to change without prior notice due to improvements or other reasons. This document has been carefully prepared and the information contained is believed to be accurate. In rare cases, however, there may be inaccuracies such as text errors. Before using these products, always contact us for the delivery specification sheet to check the latest specifications.

The product warranty is valid for one year after delivery and is limited to product repair or replacement for defects discovered and reported to us within that one year period. However, even if within the warranty period we accept absolutely no liability for any loss caused by natural disasters or improper product use. Copying or reprinting the contents described in this material in whole or in part is prohibited without our prior permission.

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